

View Online at <https://aerobasegroup.com/nsn/5961-01-432-9120>

Inclosure Material:

Metal all transistor

Overall Length:

0.875 inches all transistor

Terminal Length:

0.500 inches all transistor and 0.750 inches all transistor

Overall Diameter:

0.335 inches all transistor and 0.370 inches all transistor

Internal Configuration:

Junction contact all transistor

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-39 all transistor

Internal Junction Configuration:

Npn all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal

Terminal Circle Diameter:

0.016 inches all transistor and 0.021 inches all transistor

Features Provided:

Electrostatic sensitive

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

40.0 collector to base voltage, dc all transistor and 20.0 collector to emitter voltage, dc all transistor and 3.0 emitter to base voltage, dc all transistor

Current Rating Per Characteristic:

0.40 amperes source cutoff current all transistor

Nuclear Hardness Critical Feature:

Hardened

Terminal Type And Quantity:

3 uninsulated wire lead all transistor

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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